



3.0A SCHOTTKY BARRIER RECTIFIER

Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low-Power Loss, High Efficiency
- High-Surge Capability
- High-Current Capability and Low-Forward Voltage Drop
- Surge Overload Rating to 80A Peak
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: DO-201AD
- Package Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Tin. Solderable per MIL-STD-202, Method 208 (3)
- Polarity: Cathode Band
- Weight: 1.1 grams (Approximate)

Ordering Information (Note 3)

Doub Normalian	Dookene	Packing		
Part Number Package	Qty.	Carrier		
SB380-T	DO-201AD	1.2K	13" Tape & Reel	
SB3100-T	DO-201AD	1.2K	13" Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Maximum Ratings and Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteris	tic	Symbol	SB380	SB3100	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	80	100	V
RMS Reverse Voltage		V _R (RMS)	56	70	V
Average Rectified Output Current (Note 4)	@ T _L = +80°C	lo	3	.0	Α
Non-Repetitive Peak Forward Surge (Single Half Sine-Wave Superimposed		IFSM	1	00	А
Forward Voltage	@ $I_F = 3.0A$	V _{FM}	0.	79	V
Peak Reverse Current at Rated DC Blocking Voltage	@ T _A = +25°C @ T _A = +100°C	I _{RM}		.5 20	mA
Typical Junction Capacitance (Note 5)	Сл	2	50	pF

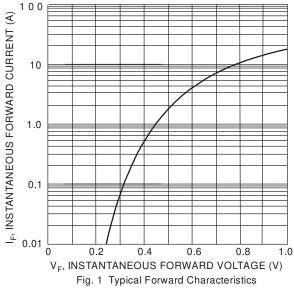
Notes:

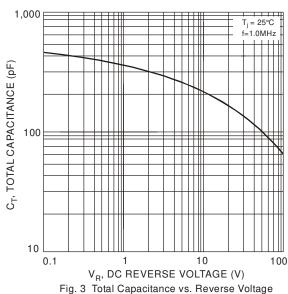
- 4. Measured at ambient temperature at a distance of 9.5mm from the case.
- 5. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.

Thermal Characteristics

Characteristic	Symbol	SB380	SB3100	Unit
Typical Thermal Resistance Junction to Ambient	RθJA	2		K/W
Operating and Storage Temperature Range	TJ, TSTG	-65 to	+150	°C







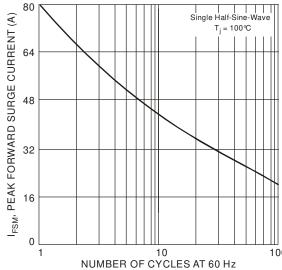
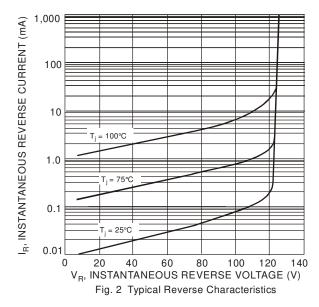
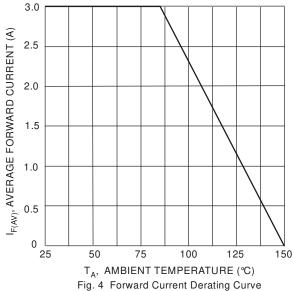


Fig. 5 Max Non-Repetitive Peak Forward Surge Current



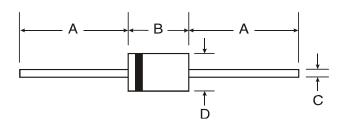




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

DO-201AD



DO-201 AD				
Dim	Min	Max		
Α	25.40	_		
В	7.20	9.50		
C	1.20	1.30		
D	4.80	5.30		
All Dimensions in mm				



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